Code: 15A04301



R15

B.Tech II Year I Semester (R15) Regular & Supplementary Examinations November/December 2017

ELECTRONIC DEVICES & CIRCUITS

(Common to EEE, ECE and EIE)

Time: 3 hours Max. Marks: 70

PART - A

(Compulsory Question)

- 1 Answer the following: $(10 \times 02 = 20 \text{ Marks})$
 - (a) Define static and dynamic resistance of diode.
 - (b) List the applications of zener diode.
 - (c) What is rectifier?
 - (d) List out different filters used in association with rectifiers.
 - (e) Define alpha and beta DC amplification factors of BJT.
 - (f) Compare BJT and FET.
 - (g) What is the need of biasing?
 - (h) What is thermal runaway?
 - (i) Draw BJT transistor small signal low frequency hybrid model.
 - (j) Draw JFET transistor small signal low frequency hybrid model.

PART - B

(Answer all five units, 5 X 10 = 50 Marks)

UNIT – I

- 2 (a) With neat diagrams, explain the operation of p-n junction diode considering different biasing conditions.
 - (b) Illustrate V-I characteristics of p-n junction diode.

OR

- 3 Discuss the operation and characteristics of the following:
 - (a) SCR.
 - (b) UJT.

UNIT – II

- 4 (a) With the help of a neat circuit diagram, input and output waveforms, describe the operation of Half-wave rectifier.
 - (b) Derive the expressions for ripple factor and maximum efficiency of HWR.

OR

- 5 (a) Design a Full-wave center-tap rectifier with capacitor filter and then explain its operation.
 - (b) Derive the expression for ripple factor of a Full-wave center-tap rectifier with capacitor filter and then comment on the result.

UNIT – III

6 Illustrate the input and output characteristics of all three configurations of a BJT transistor. Also give the important equations related to those configurations.

OR

- 7 (a) Explain the construction and operation of n-channel JFET.
 - (b) Draw and explain the drain and transfer characteristics of n-channel JFET.

[UNIT - IV]

- 8 (a) Design a common emitter BJT circuit with self bias and then explain its operation.
 - (b) Derive the expression for stability factor S of self bias circuit.

OR

9 List out different FET biasing methods and then explain the same.

[UNIT - V]

By performing generalized analysis of transistor amplifier, derive the expression for different gains and impedances.

OF

- 11 (a) Design and analyze common source JFET amplifier for its gains and impedances.
 - (b) Compare CE, CB and CC amplifiers.
